## STRUCTURAL, OPTICAL AND ELECTRICAL PROPERTIES OF MOLECULAR HYBRID FILMS BASED ON RARE EARTH QUINOLINE COMPLEXES (REQ<sub>3</sub>) CHELATED WITH BIDENTATE LIGANDS

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#### Abstract

The molecular hybrid compound based on metal quinoline, Mq<sub>3</sub> complexes were expected to give good electroluminescence and carrier transport properties. However, obtaining pure emission colour from the metal quinolinate complexes has always been a problem because most of the materials exhibit broad emission spectra with a full width at half maximum (FWHM) around 50-200 nm. The combined properties of rare earth as the metal centre and tris-(8-hydroxyquinolates) (8Hq) as the chelating ligand (centre ligand) as well as the adduction of the bidentate ligand which are 1,10-phenanthroline (Phen) and 2,2- bipyridine (Bpy) as the secondary ligand make these rare earth quinoline (Req<sub>3</sub>) ternary complexes ideal for use in optoelectronic devices. In this work, four different Req<sub>3</sub> ternary complexes namely, Euq<sub>3</sub>bpy<sub>3</sub>, Euq<sub>3</sub>phen<sub>3</sub>, Tbq<sub>3</sub>bpy<sub>3</sub> and Tbq<sub>3</sub>phen<sub>3</sub> were synthesized and coated as thin films by spin coating technique. The FTIR and XRD measurements were performed in order to study the spectroscopic and structural nature of the film. The thermal properties were evaluated from TGA/DTG analysis. The UV-Vis and PL measurement were also carried out. UV-Vis absorption results reveal that the absorption process of the  $Req_3$  complexes are dominated by the neutral ligand (secondary ligand) indicating that chelated ligand has overcome the limitation of an intrinsically absorption coefficient for the rare earth metals  $(Re^{3+})$ . It is also proven that the different degree in the green coloured fluorescence detected in the PL spectra is due to the fact that the energy transfer between the triplet state and the  $Re^{3+}$ is inefficient. The J-V characteristics of Req<sub>3</sub> ternary complexes film are also investigated. The Richardson-Schottky thermionic emission is found to dominate the transport mechanism. The electronics parameters of the ITO/Req<sub>3</sub> ternary complexes/Al are also extracted from the conventional ln J- V and Cheung's functions.

#### Abstrak

Kompleks hibrid logam quinoline, Mq<sub>3</sub> dijangka akan memberikan ciri-ciri elektroluminensi dan angkutan pembawa yang baik. Walaubagaimanapun, adalah sukar untuk memperolehi pancaran warna tulen daripada bahan ini yang kebanyakannya memaparkan spektrum pancaran yang lebar penuh pada maksimum setengah (FWHM) di antara 50-200 nm. Gabungan ciri-ciri daripada logam nadir bumi, Re<sup>3+</sup> sebagai pusat logam dan tris-(8-hydroxyquinolates) (8Hq) sebagai ligan pusat dan juga bidentate ligan sebagai ligan neutral menjadikan kompleks nadir bumi quinoline ternari Req<sub>3</sub> ini sesuai digunakan untuk aplikasi optoelektronik. Di dalam penyelidikan ini, empat jenis Req<sub>3</sub> iaitu Euq<sub>3</sub>bpy<sub>3</sub>, Euq<sub>3</sub>phen<sub>3</sub>, Tbq<sub>3</sub>bpy<sub>3</sub> and Tbq<sub>3</sub>phen<sub>3</sub> telah disentesis dan dijadikan filem nipis dengan mengunakan kaedah salutan putaran. Pengukuran transformasi inframerah Fourier (FTIR) dan analisis belauan sinar-x (XRD) telah digunakan untuk mengkaji spektroskopi dan jenis struktur filem tersebut. Sifat haba bahan tersebut dikaji melalui analisis termogravimetrik (TGA / DTG). Pangukuran penyerapan ultra-lembayungnampak (UV-Vis) dan fotoluminensi (PL) juga dijanakan. Daripada pengukuran UV-Vis, didapati proses penyerapan kompleks ternari Req<sub>3</sub> didominasi oleh ligan neutral. Ini menunjukkan bahawa ligan tersebut telah mengatasi had penyerapan logam  $Re^{3+}$ . Selain itu, warna hijau berpendaflour yang berbeza juga telah dikesan di dalam spektra PL disebabkan oleh pemindahan tenaga diantara keadaan triplet dan logam Re<sup>3+</sup> adalah tidak cekap. Kajian keatas pengukuran J-V bagi ITO/Req<sub>3</sub>/Al juga dibuat. Mekanisme Richardson-Schottky termionik didapati mendominasi kesuluruhan mekanisma angkutan. Parameter elektronik juga di ekstrak dari keadah konvensional ln J- V dan fungsi Cheung.

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## List of abbreviations

Eu	Europium
Tb	Terbium
8Hq	8-hydroxyquinoline
Phen	1,10- phenanthroline
Вру	2,2-bipyridine
$Mq_3$	Metal (III) Tris-(8-hydroxyquinoline)
Req <sub>3</sub>	Rare earth (III) Tris-(8-hydroxyquinoline) / rare earth quinoline
Erq <sub>3</sub>	Erbium (III) Tris-(8-hydroxyquinoline) / erbium quinoline
Euq <sub>3</sub>	Europium (III) Tris-(8-hydroxyquinoline) / europium quinoline
Tbq <sub>3</sub>	Terbium (III) Tris-(8-hydroxyquinoline) / terbium quinoline
Euq <sub>3</sub> phen <sub>3</sub>	Europium (III) Tris-(8-hydroxyquinoline)-Tris-(1,10-phenanthroline)
Tbq <sub>3</sub> phen <sub>3</sub>	Terbium (III) Tris-(8-hydroxyquinoline)-Tris-(1,10-phenanthroline)
Euq <sub>3</sub> bpy <sub>3</sub>	Europium (III) Tris-(8-hydroxyquinoline)-Tris-(2,2-bipyridine)
Tbq <sub>3</sub> bpy <sub>3</sub>	Terbium (III) Tris-(8-hydroxyquinoline)-Tris-(2,2-bipyridine)
R-S	Richardson Schottky
F-N	Fowler Nordheim
SCLC	Space charge limited current
TFSCLC	trapped filled space charge limited current
P-F	Poole Frenkel

#### List of publications

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